

# SMD15PL THRU SMD1200PL

**GM** GarboMicro  
Semiconductor

## 1 Amp Schottky Rectifier

### Features

- Schottky Barrier Rectifier
- High Current Capability
- Low Forward Voltage
- Lead Free Finish/RoHS Compliant (Note 1) ("P" Suffix designates RoHS Compliant. See ordering information)
- Epoxy meets UL 94 V-0 flammability rating
- Moisture Sensitivity Level 1

### Maximum Ratings

- Operating Temperature: -55°C to +125°C
- Storage Temperature: -55°C to +150°C
- Maximum Thermal Resistance; 28°C/W Junction To Lead

GM Catalog Number	Device Marking	Maximum Recurrent Peak Reverse Voltage	Maximum RMS Voltage	Maximum DC Blocking Voltage
SMD15PL	D5	50V	35V	50V
SMD16PL	D6	60V	42V	60V
SMD18PL	D8	80V	56V	80V
SMD110PL	D10	100V	70V	100V
SMD1150PL	D15	150V	105V	150V
SMD1200PL	D20	200V	140V	200V

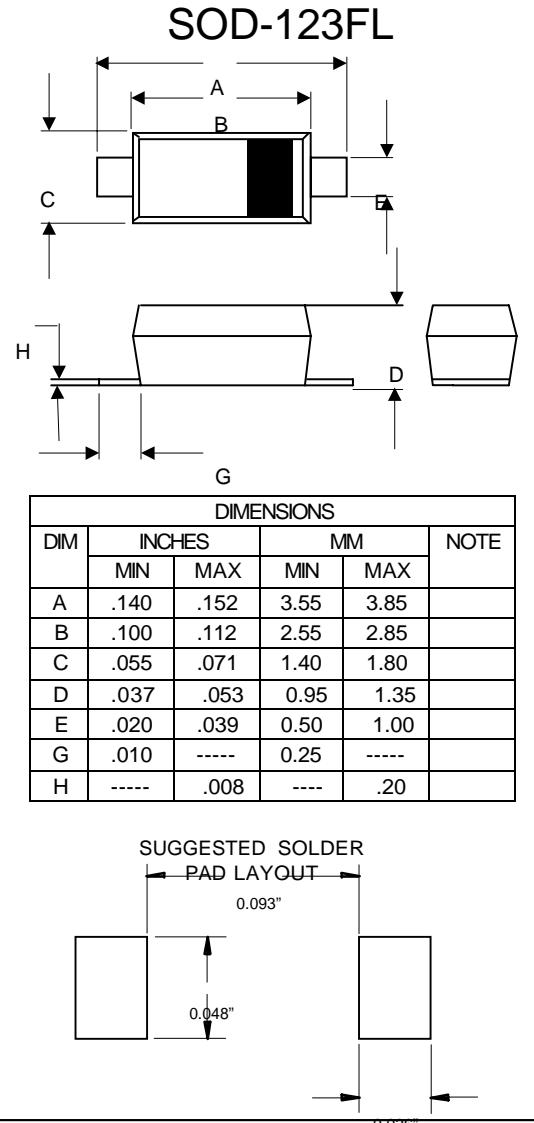
### Electrical Characteristics @ 25°C Unless Otherwise Specified

Average Forward Current	$I_{F(AV)}$	1.0A	$T_L = 90^\circ\text{C}$
Peak Forward Surge Current	$I_{FSM}$	30A	8.3ms, half sine
Maximum Instantaneous Forward Voltage SMD15PL-16PL SMD18PL-1150PL SMD1200PL	$V_F$	.70V .85V .95V	$I_{FM} = 1.0\text{A};$ $T_J = 25^\circ\text{C}$ (Note:2)
Maximum DC Reverse Current At Rated DC Blocking Voltage	$I_R$	0.5mA 20mA	$T_A = 25^\circ\text{C}$ $T_A = 100^\circ\text{C}$
Typical Junction Capacitance SMD12PL -16PL SMD18PL-1150PL	$C_J$	110pF 30pF	Measured at 1.0MHz, $V_R=4.0\text{V}$

Note:1.High Temperature Solder Exemption Applied, see EU Directive Annex 7.

2.Pulse test: Pulse width 300 sec, Duty cycle 2%

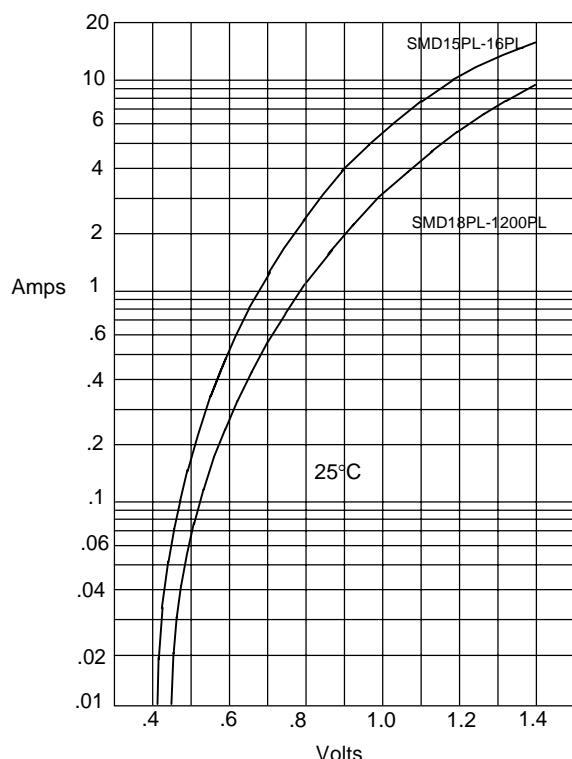
## 1 Amp Schottky Rectifier 50 to 200 Volts



# SMD15PL thru SMD1200PL

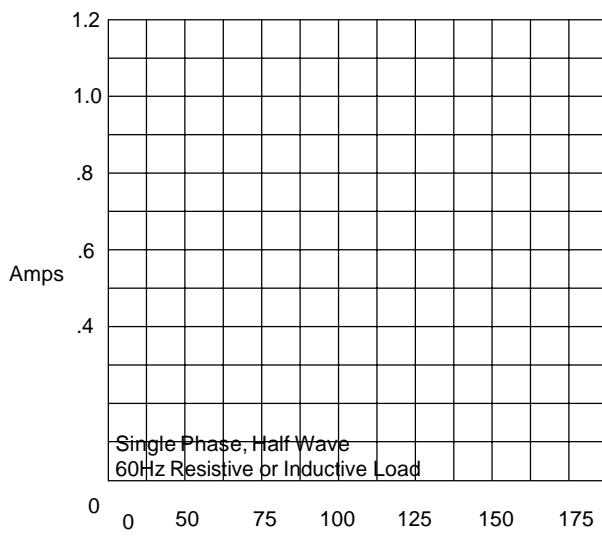
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Figure 1  
Typical Forward Characteristics



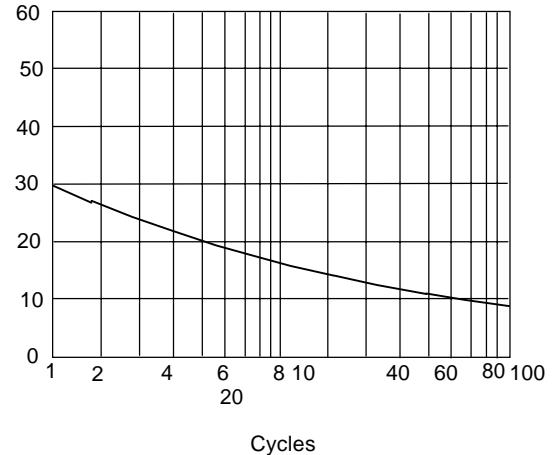
Instantaneous Forward Current - Amperesversus  
Instantaneous Forward Voltage - Volts

Figure 2  
Forward Derating Curve



Average Forward Rectified Current - Amperesversus  
Lead Temperature - °C

Figure 3  
Peak Forward Surge Current



Number Of Cycles At 60Hz - Cycles